



3.3V CMOS QUAD 2-INPUT NAND GATE (OPEN DRAIN) WITH 5 VOLT TOLERANT I/O

IDT74LVC38A
ADVANCE
INFORMATION

FEATURES:

- 0.5 MICRON CMOS Technology
- ESD > 2000V per MIL-STD-883, Method 3015;
> 200V using machine model (C = 200pF, R = 0)
- 1.27mm pitch SOIC, 0.65mm pitch SSOP and
0.65mm pitch TSSOP packages
- Extended commercial range of - 40°C to +85°C
- Vcc = 3.3V ±0.3V, Normal Range
- Vcc = 2.3V to 3.6V, Extended Range
- CMOS power levels (0.4μW typ. static)
- Rail-to-Rail output swing for increased noise margin
- All inputs, outputs and I/O are 5 Volt tolerant
- Supports hot insertion

Drive Features for LVC38A:

- High Output Drivers: +24mA
- Reduced system switching noise

DESCRIPTION

The LVC38A quad 2-input NAND gate is built using advanced dual metal CMOS technology. This device contains four 2-input open drain NAND gates.

The LVC38A has been designed with a +24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

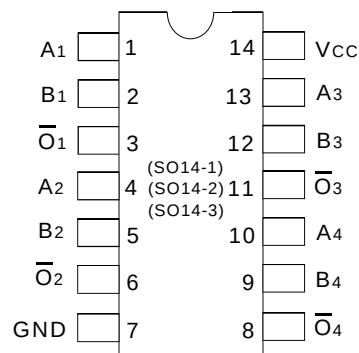
APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- Data communication and telecommunication systems

Functional Block Diagram



PIN CONFIGURATION



FUNCTION TABLE (1)

Inputs		Outputs (2)
Ax	Bx	Ox (R to Vcc)
L	L	H
X	H	L
H	X	L
H	H	L

NOTES:

1. H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
2. Open drain output requires pull-up resistors.

SOIC/ SSOP/ TSSOP
TOP VIEW

PIN DESCRIPTION

Pin Number	Description
Ax, Bx	Data Inputs
Ox	Outputs (Active LOW)

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Symbol	Description	Max.	Unit
V _{TERM} ⁽²⁾	Terminal Voltage with Respect to GND	– 0.5 to +6.5	V
V _{TERM} ⁽³⁾	Terminal Voltage with Respect to GND	– 0.5 to +6.5	V
T _{STG}	Storage Temperature	– 65 to +150	°C
I _{OUT}	DC Output Current	– 50 to +50	mA
I _{IK} I _{OK}	Continuous Clamp Current, V _I < 0 or V _O < 0	– 50	mA
I _{CC} I _{SS}	Continuous Current through each V _{CC} or GND	±100	mA

LVC QUAD Link

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{CC} terminals.
- All terminals except V_{CC}.

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	4.5	6	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	5.5	8	pF
C _{I/O}	I/O Port Capacitance	V _{IN} = 0V	6.5	8	pF

LVC QUAD Link

NOTE:

- As applicable to the device type.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: T_A = – 40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V _{IH}	Input HIGH Voltage Level	V _{CC} = 2.3V to 2.7V		1.7	—	—	V
		V _{CC} = 2.7V to 3.6V		2	—	—	
V _{IL}	Input LOW Voltage Level	V _{CC} = 2.3V to 2.7V		—	—	0.7	V
		V _{CC} = 2.7V to 3.6V		—	—	0.8	
I _{IH} I _{IL}	Input Leakage Current	V _{CC} = 3.6V	V _I = 0 to 5.5V	—	—	±5	μA
I _{OZH} I _{OZL}	High Impedance Output Current (3-State Output pins)	V _{CC} = 3.6V	V _O = 0 to 5.5V	—	—	±10	μA
I _{OFF}	Input/Output Power Off Leakage	V _{CC} = 0V, V _{IN} or V _O ≤ 5.5V		—	—	±50	μA
V _{IK}	Clamp Diode Voltage	V _{CC} = 2.3V, I _{IN} = – 18mA		—	– 0.7	– 1.2	V
V _H	Input Hysteresis	V _{CC} = 3.3V		—	100	—	mV
I _{CC1} I _{CC2} I _{CC3}	Quiescent Power Supply Current	V _{CC} = 3.6V	V _{IN} = GND or V _{CC}	—	—	10	μA
ΔI _{CC}	Quiescent Power Supply Current Variation	One input at V _{CC} – 0.6V other inputs at V _{CC} or GND		—	—	500	μA

LVC QUAD Link

NOTE:

- Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOL	Output LOW Voltage	V _{CC} = 2.3V to 3.6V	I _{OL} = 0.1mA	—	0.2	V
		V _{CC} = 2.3V	I _{OL} = 6mA	—	0.4	
			I _{OL} = 12mA	—	0.7	
		V _{CC} = 2.7V	I _{OL} = 12mA	—	0.4	
		V _{CC} = 3.0V	I _{OL} = 24mA	—	0.55	

NOTE:

1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range. T_A = – 40°C to +85°C.

OPERATING CHARACTERISTICS, T_A = 25°C

Symbol	Parameter	Test Conditions	V _{CC} = 2.5V±0.2V	V _{CC} = 3.3V±0.3V	Unit
			Typical	Typical	
CPD	Power Dissipation Capacitance Per Gate	C _L = 0pF, f = 10MHz	—	—	pF

SWITCHING CHARACTERISTICS (1, 2)

Symbol	Parameter	(RL = 500Ω, CL = 30pf)		(RL = 500Ω, CL = 50pf)				Unit
		Vcc = 2.5V±0.2V		Vcc = 2.7V		Vcc = 3.3V±0.3V		
		Min	Max	Min	Max	Min	Max	
tPLH	Propagation Delay	—	—	—	6	—	5.2	ns
tPHL	Ax to Bx to $\overline{O}x$	—	—	—	—	—	—	—
tsk(o)	Output Skew ⁽³⁾	—	—	—	—	—	500	ps

NOTES:

1. See test circuits and waveforms. T_A = – 40°C to + 85°C.
2. Switching characteristics are measured with pull up resistors all identical to within 1%.
3. Skew between any two outputs of the same package and switching in the same direction.

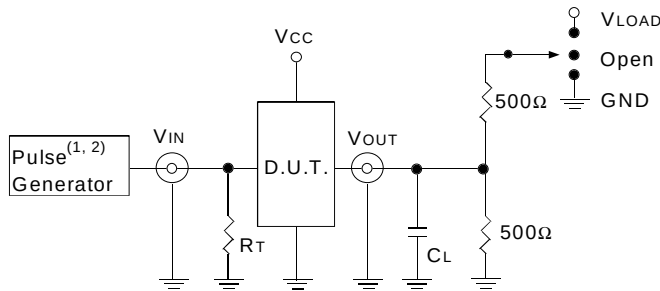
TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	V _{CC} (1)= 2.5V ±0.2V	V _{CC} (2)= 3.3V ±0.3V & 2.7V	Unit
V _{LOAD}	2 x V _{CC}	6	V
V _{IH}	V _{CC}	2.7	V
V _T	V _{CC} / 2	1.5	V
V _{LZ}	150	300	mV
V _{HZ}	150	300	mV
C _L	30	50	pF

LVC QUAD Link

TEST CIRCUITS FOR ALL OUTPUTS



LVC QUAD Link

DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

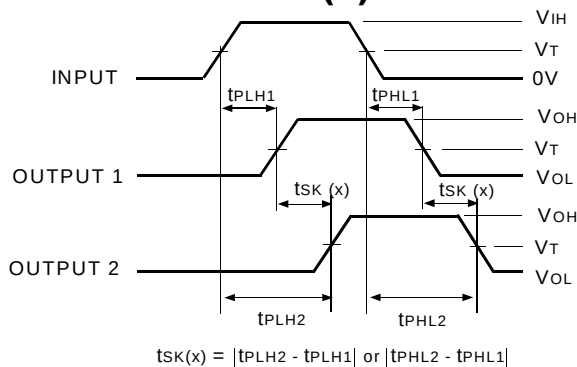
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_r ≤ 2ns; t_r ≤ 2ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_r ≤ 2.5ns; t_r ≤ 2.5ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	V _{LOAD}
Disable High Enable High	GND
All Other tests	Open

LVC QUAD Link

OUTPUT SKEW - t_{SK}(x)



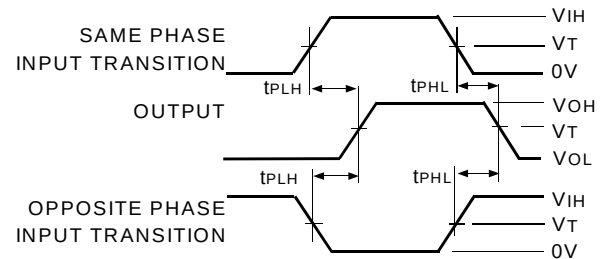
$$t_{SK}(x) = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

NOTES:

1. For t_{SK}(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For t_{SK}(b) OUTPUT1 and OUTPUT2 are in the same bank.

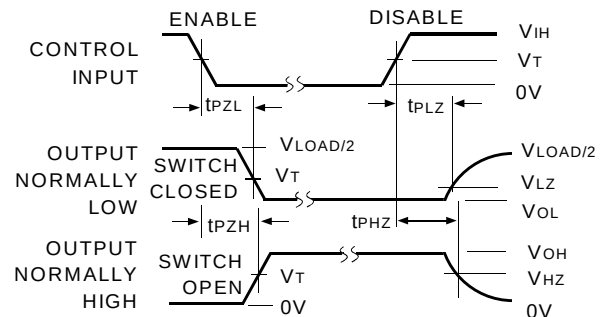
LVC QUAD Link

PROPAGATION DELAY



LVC QUAD Link

ENABLE AND DISABLE TIMES

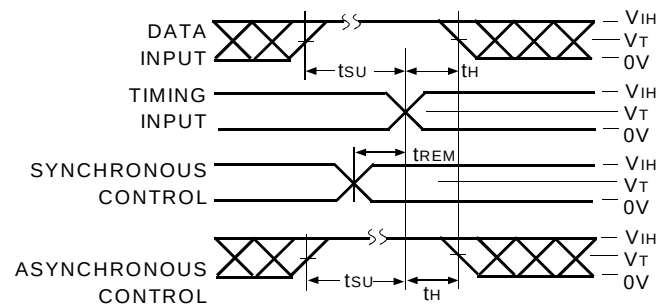


LVC QUAD Link

NOTE:

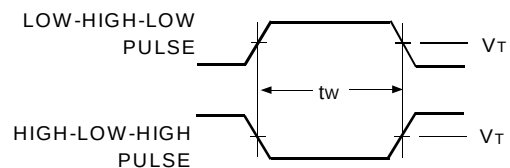
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SET-UP, HOLD, AND RELEASE TIMES



LVC QUAD Link

PULSE WIDTH



LVC QUAD Link

ORDERING INFORMATION

IDT	XX	LVC	XXX	XX	
Temp. Range		Device Type		Package	
				DC	Small Outline IC (SO14-1)
				PY	Shrink Small Outline Package (SO14-2)
				PG	Thin Shrink Small Outline Package (SO14-3)
			38A		Quad 2-Input NAND Gate (Open Drain), $\pm 24\text{mA}$
			74		-40°C to $+85^{\circ}\text{C}$



CORPORATE HEADQUARTERS
2975 Stender Way
Santa Clara, CA 95054

for SALES:
800-345-7015 or 408-727-6116
fax: 408-492-8674
www.idt.com*

*To search for sales office near you, please click the sales button found on our home page or dial the 800# above and press 2.
The IDT logo is a registered trademark of Integrated Device Technology, Inc.